

GPDP3320

RECTIFIER DIODE

VOLTAGE UP TO 2200 V
 AVERAGE CURRENT 3200 A
 SURGE CURRENT 31 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V_{RRM}	Repetitive peak reverse voltage	2200 V
V_{RSM}	Non-repetitive peak reverse voltage	2200 V
I_{RRM}	Repetitive peak reverse current, max.	75 mA

FORWARD CHARACTERISTICS

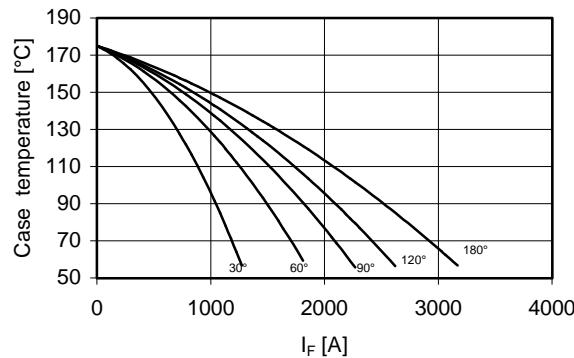
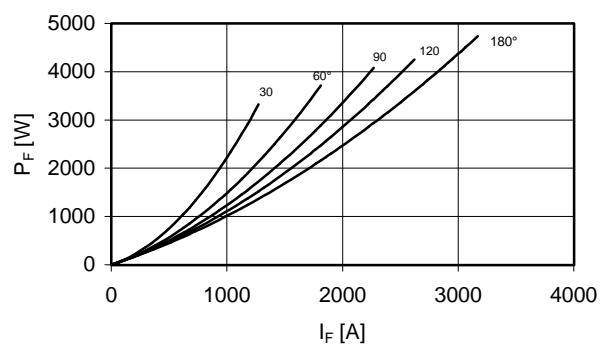
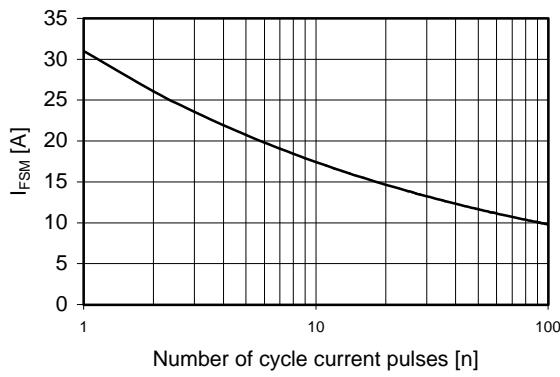
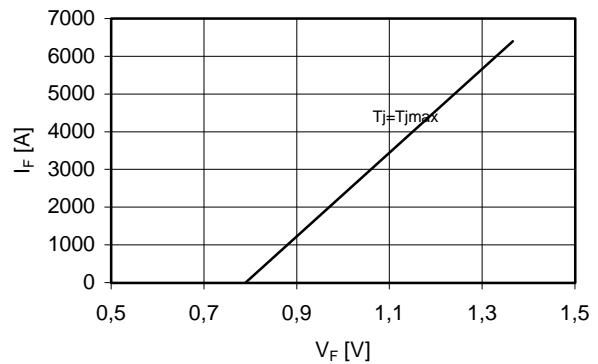
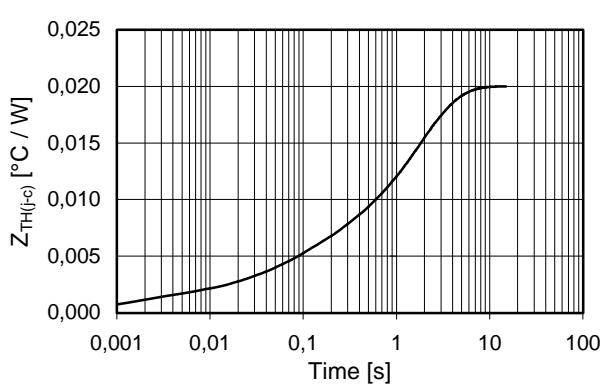
$I_{F(AV)}$	Average forward current	Sine wave, 180° conduction, $T_h = 55^\circ C$	3200 A
$I_{F(AV)}$	Average forward current	Sine wave, 180° conduction, $T_c = 85^\circ C$	2975 A
I_{FSM}	Surge forward current	Non rep. half sine wave, 50 Hz, $V_R = 0 V$, $T_j = T_{jmax}$	31 kA
$I^2 t$	$I^2 t$ for fusing coordination		4805 kA ² s
$V_{F(TO)}$	Threshold voltage	$T_j = T_{jmax}$	0,79 V
r_F	Forward slope resistance	$T_j = T_{jmax}$	0,09 mΩ
V_{FM}	Peak forward voltage, max	Forward current $I_F = 4000 A$, $T_j = 25^\circ C$	1,20 V

SWITCHING CHARACTERISTICS

Q_{rr}	Reverse recovery charge, typ	$T_j = T_{jmax}$, $I_F = 2000 A$, $di/dt = -5 A/\mu s$	1900 μC
I_{rr}	Reverse recovery current	$V_R = 100 V$	A
t_{rr}	Reverse recovery time		μs
V_{FP}	Forward recovery voltage	$T_j = T_{jmax}$, $di/dt = A/\mu s$	V

THERMAL AND MECHANICAL CHARACTERISTICS

$R_{th(j-c)}$	Thermal resistance (junction to case)	Double side cooled	0,02 °C/W
$R_{th(c-h)}$	Thermal resistance (case to heatsink)	Double side cooled	0,005 °C/W
T_{jmax}	Max operating junction temperature		175 °C
T_{stg}	Storage temperature		-40 / 175 °C
F	Clamping force ± 10%		22 kN
	Mass		500 g

Current rating - sine wave

Power loss - sine wave

**Maximum surge current
d.s. cooled**

Forward voltage drop

Thermal Impedance (j-c)

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In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.